



**COLLEGE OF ENGINEERING AND TECHNOLOGIES**  
**ALMUSTAQBAL UNIVERSITY**

**Electronics**

**CTE 207**

**Lecture 11**

**- Full-Wave Rectifier (Bridge Rectifier) -  
(2023 - 2024)**

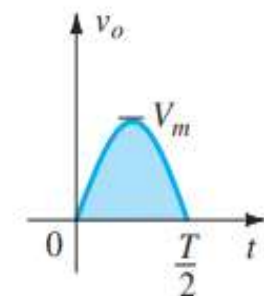
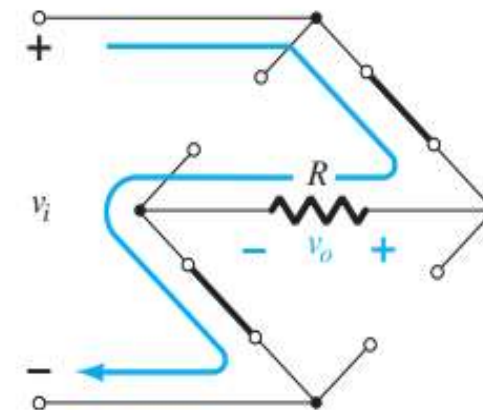
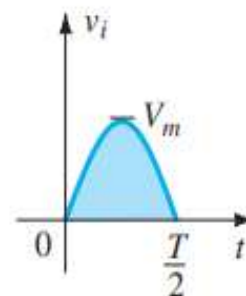
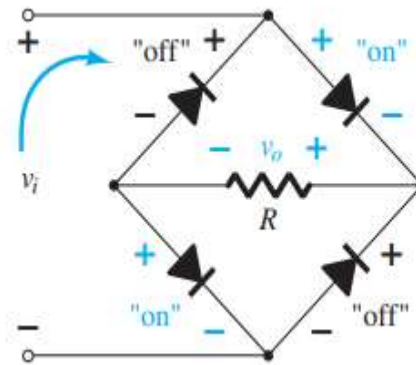
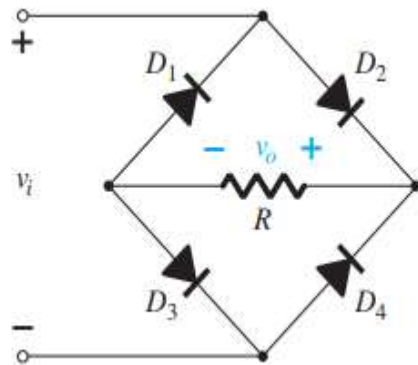
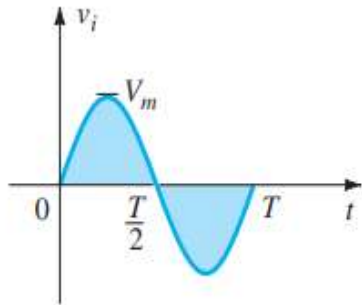
Dr. Zaidoon AL-Shammari

Lecturer / Researcher

[zaidoon.waleed@mustaqbal-college.edu.iq](mailto:zaidoon.waleed@mustaqbal-college.edu.iq)

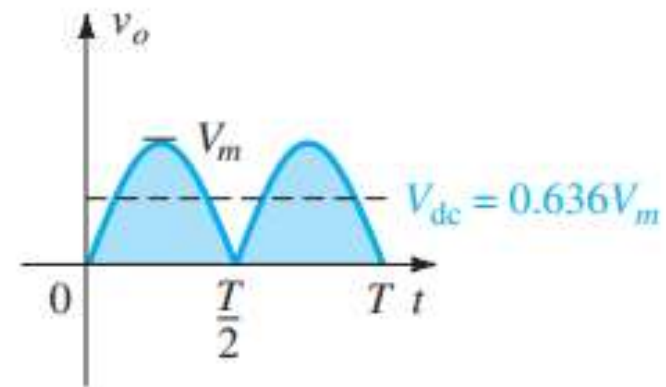
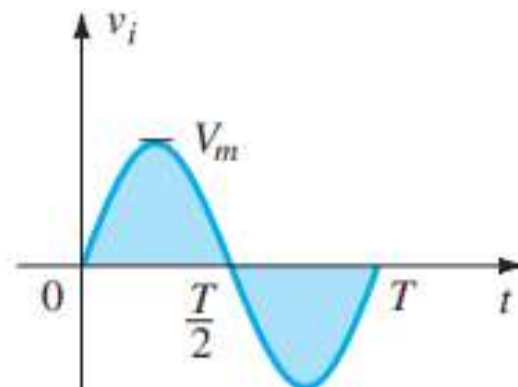
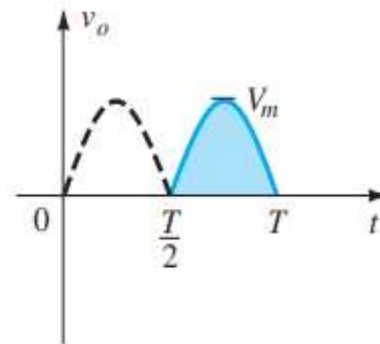
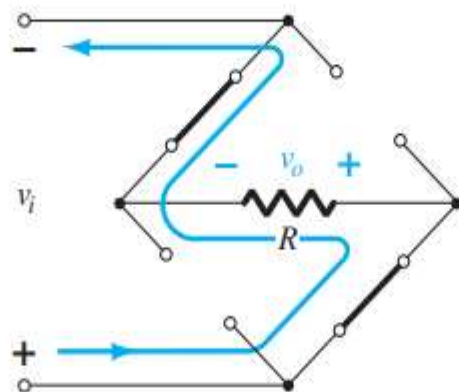
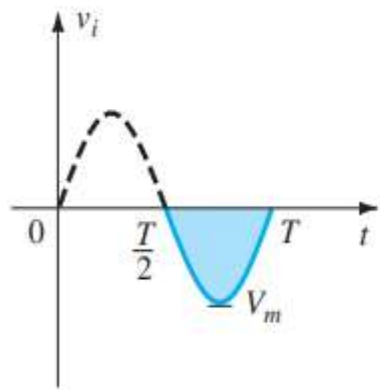
- The full-wave bridge rectifier uses four diodes, as shown in the Figure below.
- The input cycle is positive, diodes D1 and D2 are forward-biased and conduct current in the direction shown.
- A voltage is developed across RL that looks like the positive half of the input cycle.
- During this time, diodes D3 and D4 are reverse-biased.

# Positive cycle

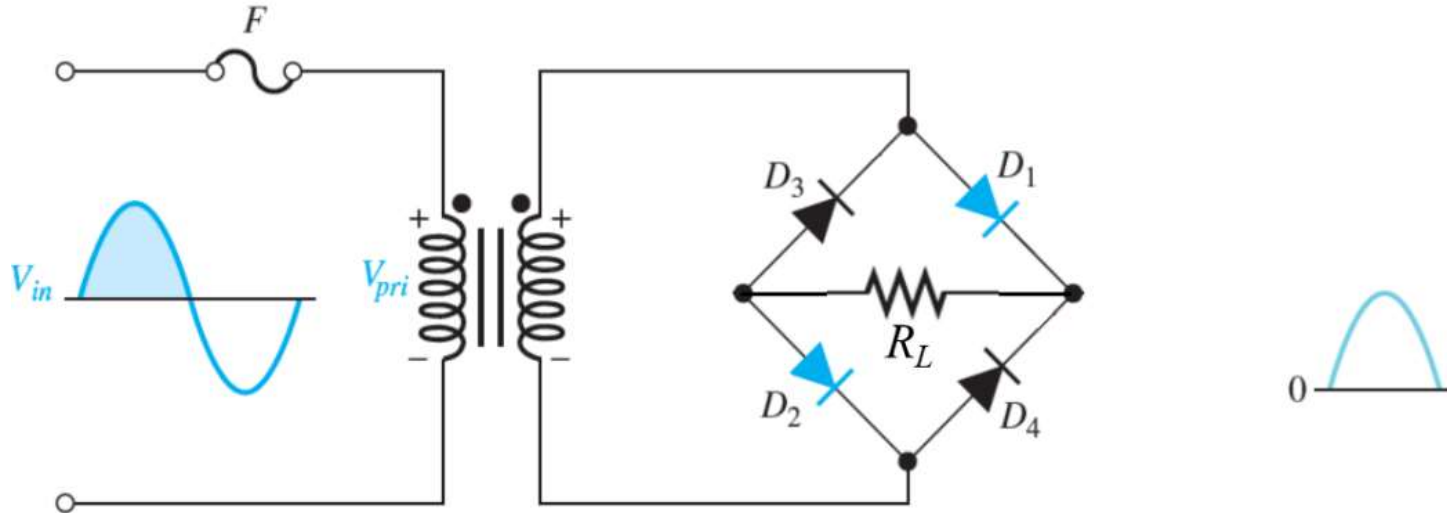


- The input cycle is negative, diodes D3 and D4 are forward-biased and conduct current in the same direction through as during the positive half-cycle.
- During the negative half-cycle, D1 and D2 are reverse-biased.
- A full-wave rectified output voltage appears across RL as a result of this action.

# Negative cycle

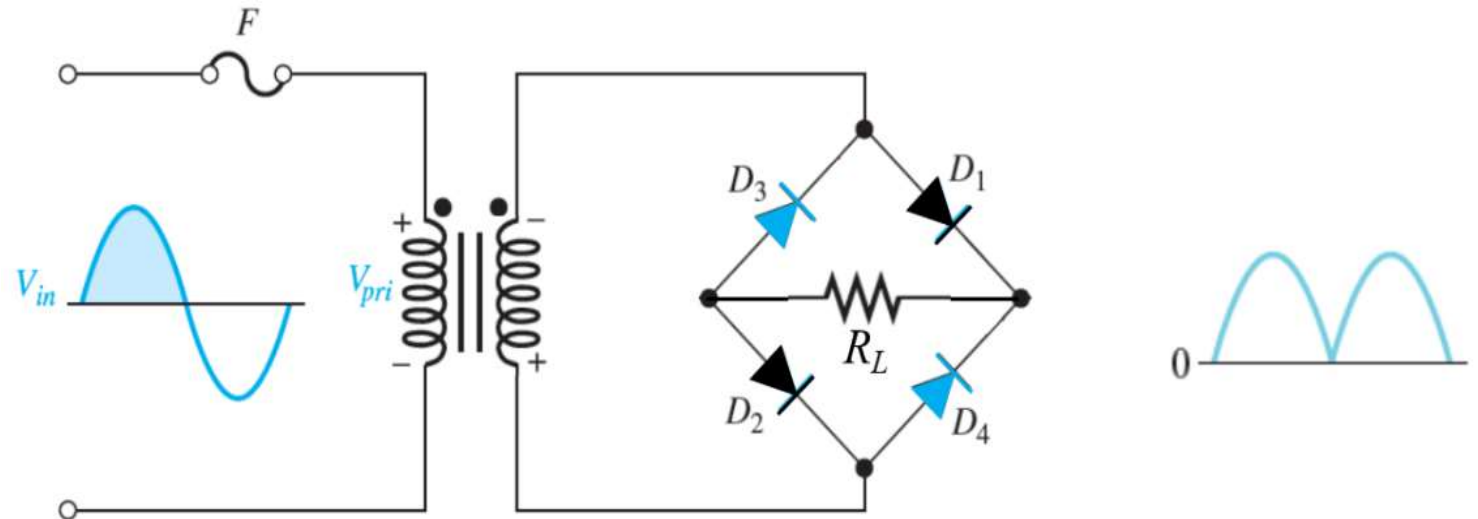


# Positive - Negative cycle



Positive cycle

Negative cycle



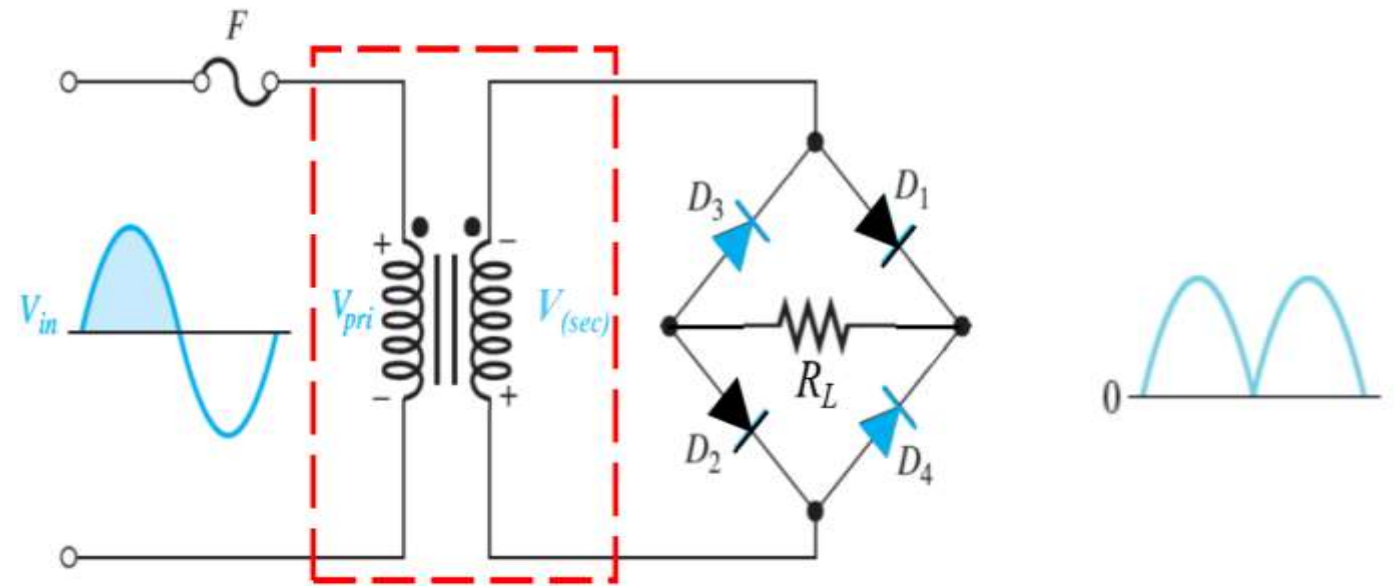
# Full-Wave Bridge Rectifier

The bridge output voltage from the transformer:

The secondary voltage is equal to the primary voltage times the turns ratio as stated by the equation:

$$V_{p(sec)} = V_{p(out)}$$

$$V_{p(sec)} = V_{p(out)} = nV_{p(pri)}$$



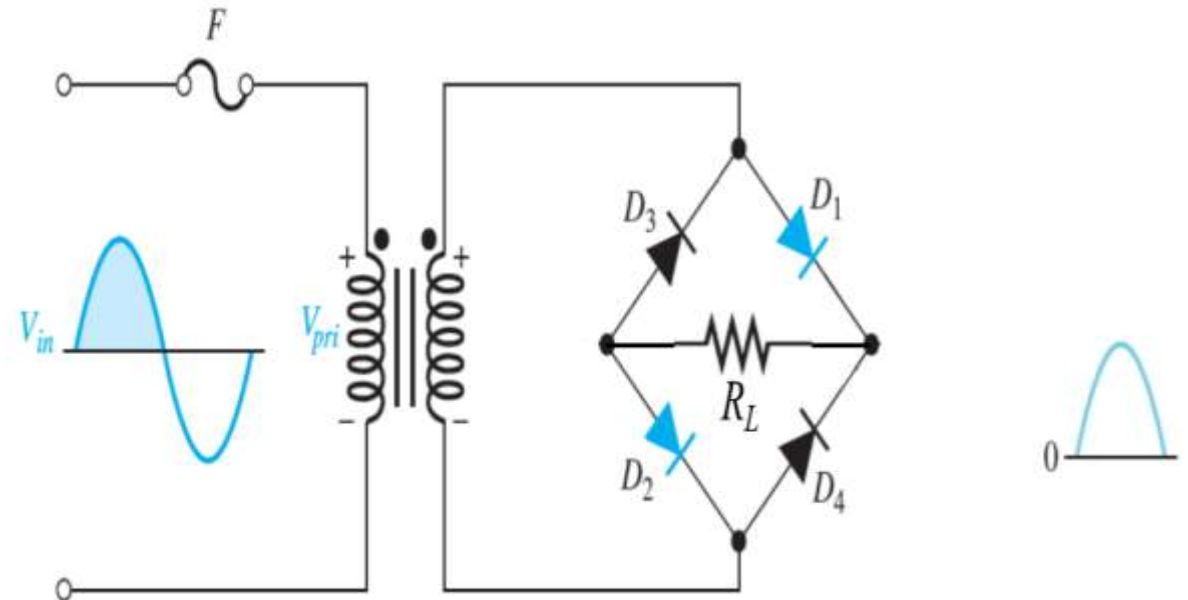
# Peak Inverse Voltage (PIV)

The positive half-cycle:

- D1 and D2 are forward-Biased
- D3 and D4 are reversed-Biased
- PIV is equal to the  $V_{p(sec)}$

which is equal to the  $V_{p(out)}$

$$PIV = V_{p(sec)} = V_{p(out)}$$

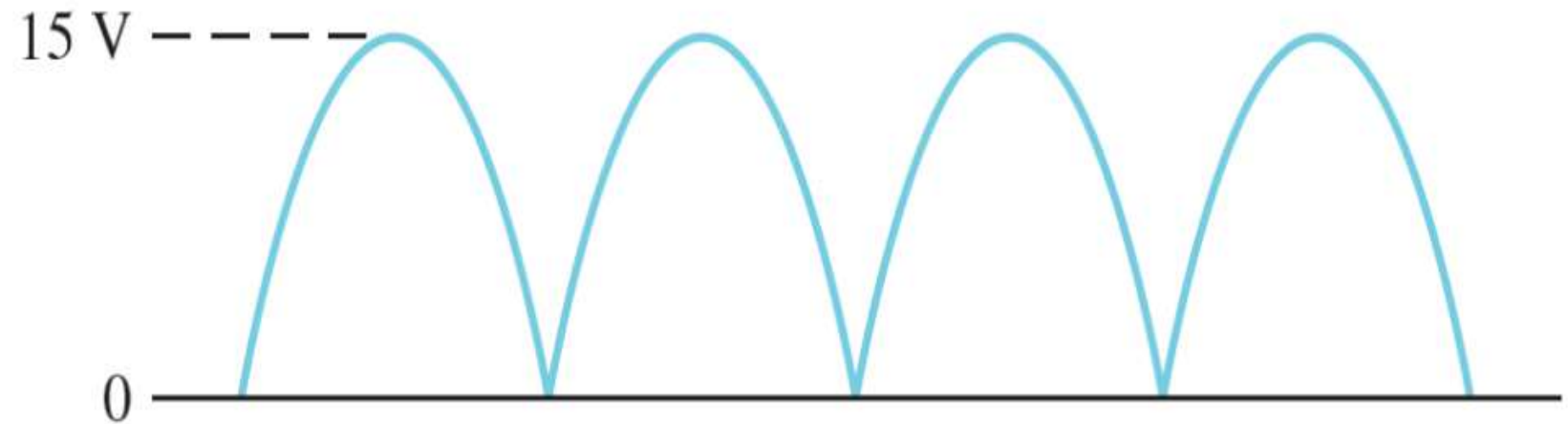




# Example

Find the average value of the full-wave rectified output voltage in the Figure below.

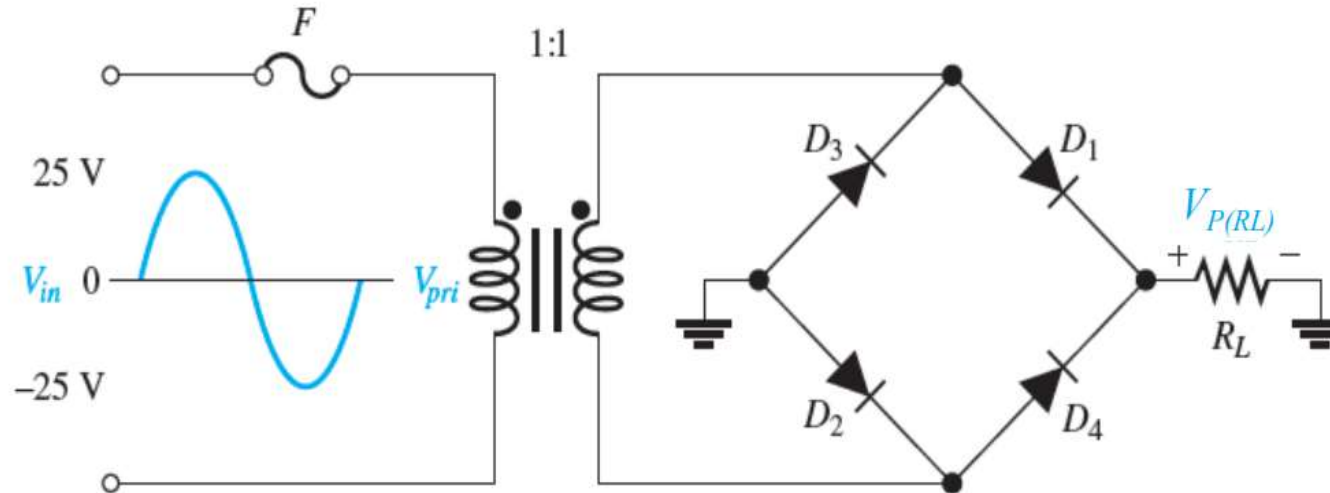
Sol:



$$V_{AVG} = \frac{2V_{p(out)}}{\pi} = \frac{2*15}{3.14} = 9.55 V$$

# Example

- a) Determine the peak output voltage  $V_p(\text{out})$ ,  $V_p(\text{RL})$  and  $V_{\text{AVG}}$  for the bridge rectifier in Figure below.
- b) What is the minimum PIV rating required for the diodes?



Sol:

$$\text{a) } V_{p(out)} = V_{p(sec)} = nV_{p(in)} = (1)25 V = 25 V$$

$$V_{p(RL)} = V_{p(out)} - 2(V_B) = 23.6 V$$

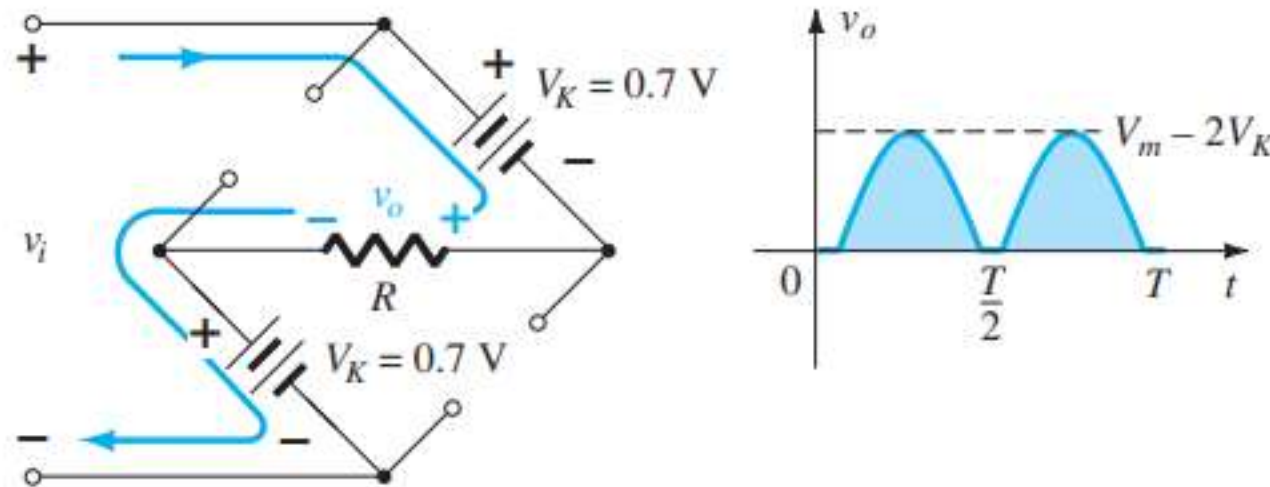
$$V_{AVG} = \frac{2V_{p(RL)}}{\pi} = \frac{47.2}{3.14} = 15 V$$

$$\text{b) } PIV = V_{p(sec)} = V_{p(out)} = 25 V$$

# Full-Wave Bridge Rectifier

If silicon rather than ideal diodes are employed as shown in Figure below, the application of Kirchhoff's voltage law around the conduction path results in

$$v_i - V_K - v_o - V_K = 0$$
$$v_o = v_i - 2V_K$$



# Full-Wave Bridge Rectifier

$$V_{dc} = 2(0.318V_m),$$

$$V_{dc} = 0.636 V_m \quad \text{full-wave}$$

The peak value of the output voltage  $V_o$  is therefore

$$V_{o_{max}} = V_m - 2V_K$$

For situations where  $V_m \gg 2V_K$ , the following equation can be applied for the average value with a relatively high level of accuracy:

$$V_{dc} \cong 0.636(V_m - 2V_K)$$

# Equations

Approximate:

Silicon:  $V_K = 0.7 \text{ V}$ ;  $I_D$  is determined by network.

Germanium:  $V_K = 0.3 \text{ V}$ ;  $I_D$  is determined by network.

Gallium arsenide:  $V_K = 1.2 \text{ V}$ ;  $I_D$  is determined by network.

Ideal:

$V_K = 0 \text{ V}$ ;  $I_D$  is determined by network.

For conduction:

$$V_D \geq V_K$$

Half-wave rectifier:

$$V_{dc} = 0.318V_m$$

Full-wave rectifier:

$$V_{dc} = 0.636V_m$$

